



IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

Application Serial No.09/292,132
Filing DateApril 14, 1999
Inventor..... Salman Akram et al.
AssigneeMicron Technology, Inc.
Group Art Unit.....2812
ExaminerS. Mulpuri
Attorney's Docket No.MI22-1171
Title: Methods of Forming A Transistor Gate

RESPONSE TO DECEMBER 15, 2005 FINAL OFFICE ACTION
PURSUANT TO 37 C.F.R. §1.116

To: Mail Stop AF
Commissioner for Patents
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Responsive to the Final Office Action dated December 15, 2005, Applicant amends
and remarks as follows:

AMENDMENTS

Underlines indicate insertions and ~~strikeouts~~ indicate deletions.

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